DATA SHEET

Solid State Relay OCMOS FET

PS7341-1A,PS7341L-1A

6-PIN DIP, HIGH ISOLATION VOLTAGE 1-ch Optical Coupled MOS FET

DESCRIPTION

NEC

The PS7341-1A and PS7341L-1A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7341L-1A has a surface mount type lead.

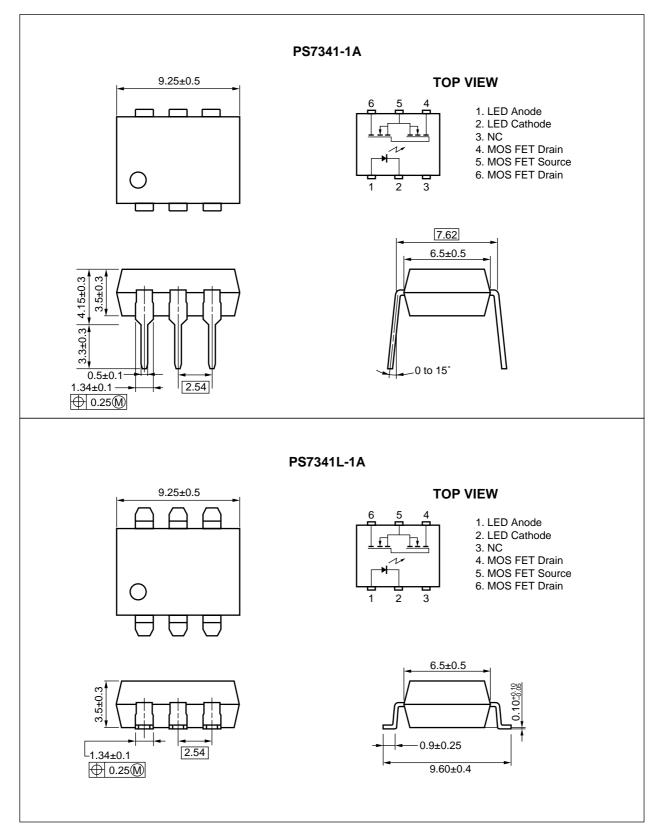
FEATURES

- High isolation voltage (BV = 3 750 Vr.m.s.)
- 1 channel type (1 a output)
- Low LED Operating Current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Small package (6-pin DIP)
- · Low offset voltage
- PS7341L-1A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8252/8253
- CSA approved: No. CA 101391

APPLICATIONS

- Exchange equipment
- Measurement equipment
- FA/OA equipment

PACKAGE DIMENSIONS (in millimeters)



***** ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number ^{*1}
PS7341-1A	6-pin DIP	Magazine case 50 pcs	PS7341-1A
PS7341L-1A			PS7341L-1A
PS7341L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7341L-1A-E4			

*1 For the application of the Safety Standard, following part number should be used.

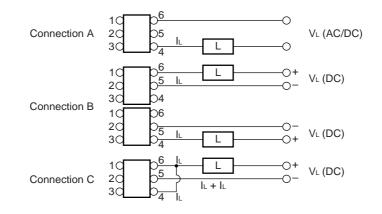
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Parameter			Symbol	Ratings	Unit
Diode	Forward Current (DC)		lf	50	mA
	Reverse Voltage		Vr	5.0	V
	Power Dissipation		PD	50	mW
	Peak Forward Current ^{*1}		IFP	1	А
MOS FET	Break Down Voltage		VL	400	V
	Continuous	Connection A	lı.	150	mA
	Load Current ^{*2}	Connection B		200	
		Connection C		300	
	Pulse Load Current ¹³ (AC/DC Connection)		Ilp	300	mA
	Power Dissipation		PD	560	mW
Isolation Vo	Isolation Voltage *4		BV	3 750	Vr.m.s.
Total Powe	Total Power Dissipation		Р⊤	610	mW
Operating A	Operating Ambient Temperature		TA	-40 to +85	°C
Storage Te	Storage Temperature		Tstg	-40 to +125	°C

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

*1 PW = 100 μ s, Duty Cycle = 1 %

*2 Conditions: IF \geq 2 mA. The following types of load connections are available.



*3 PW = 100 ms, 1 shot

*4 AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input and output

RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

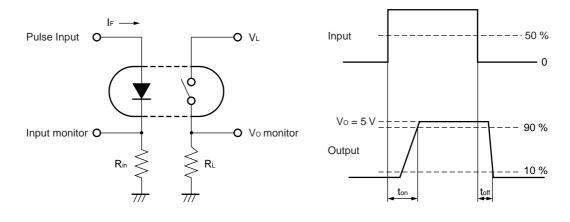
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	Ir	V _R = 5 V			5.0	μA
MOS FET	Off-state Leakage Current	Loff	V _D = 400 V		0.03	1.0	μA
	Output Capacitance	Cout	$V_{D} = 0 V, f = 1 MHz$		65		pF
Coupled	LED On-state Current	IFon	l∟ = 150 mA			2.0	mA
	On-state Resistance	Ron1	IF = 10 mA, IL = 10 mA		20	30	Ω
		Ron2	I_F = 10 mA, I_L = 150 mA, $t \leq$ 10 ms		16	25	
	Turn-on Time ^{*1}	ton	I_{F} = 10 mA, Vo = 5 V, PW \geq 10 ms		0.35	1.0	ms
	Turn-off Time ^{*1}	toff			0.03	0.2	
	Isolation Resistance	Rı-o	VI-O = 1.0 kVDC	10 [°]			Ω
	Isolation Capacitance	CI-0	V = 0 V, f = 1 MHz		1.1		pF

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*1 Test Circuit for Switching Time



75 ⁸⁵

f = 1 MHz

100

IF = 10 mA

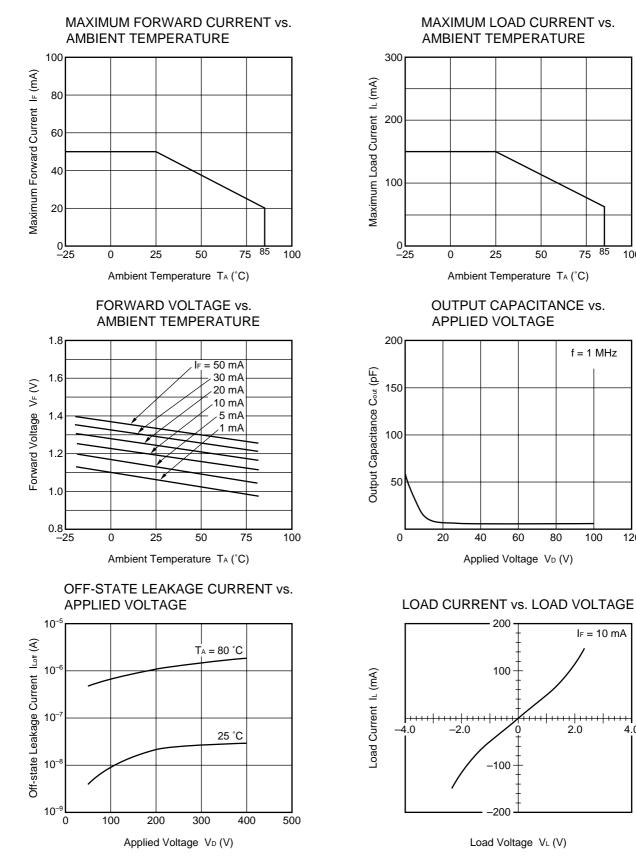
2.0

120

4.0

100

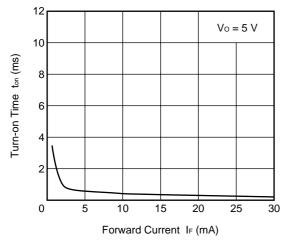
TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)



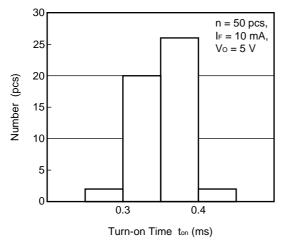
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE 3.0 ٣ Normalized to 1.0 at T_A = 25 °C, 2.5 Normalized On-state Resistance I⊧ = 10 mA, I∟ = 10 mA 2.0 1.5 1.0 0.5 0.0∟ _25 0 25 50 75 100

Ambient Temperature T_A (°C)

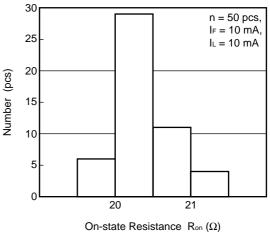
TURN-ON TIME vs. FORWARD CURRENT



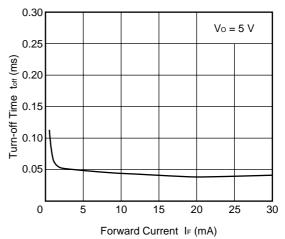
TURN-ON TIME DISTRIBUTION



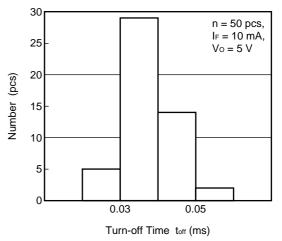
ON-STATE RESISTANCE DISTRIBUTION

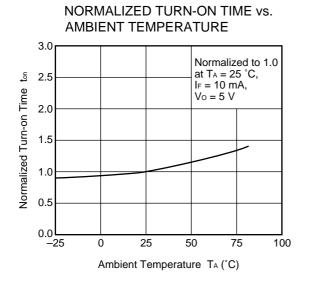


TURN-OFF TIME vs. FORWARD CURRENT

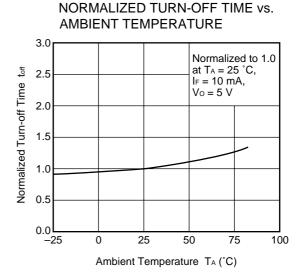


TURN-OFF TIME DISTRIBUTION

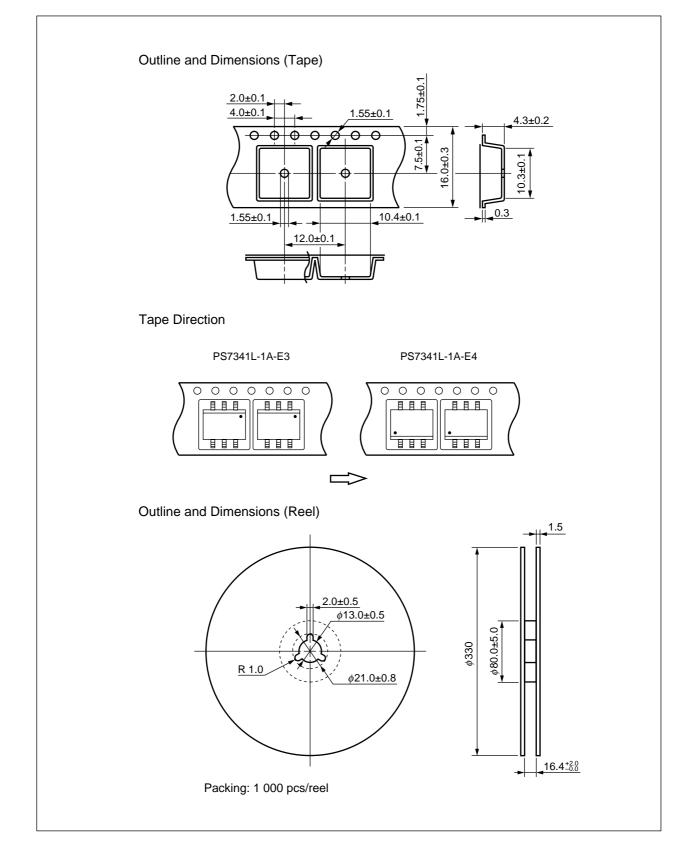




Remark The graphs indicate nominal characteristics.



***** TAPING SPECIFICATIONS (in millimeters)



RECOMMENDED SOLDERING CONDITIONS

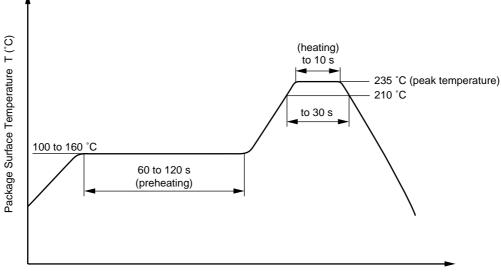
(1) Infrared reflow soldering

- · Peak reflow temperature 235 °C (package surface temperature)
- Time of temperature higher than 210 °C
- · Number of reflows
- Flux

30 seconds or less One

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow





(2) Dip soldering

- Temperature 260 °C or below (molten solder temperature)
- Time
- 10 seconds or less Number of times One
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

· Products in dry pack

After opening the dry pack, solder the products within the valid storage period specified on the label on the dry pack.

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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